



MMDTA06

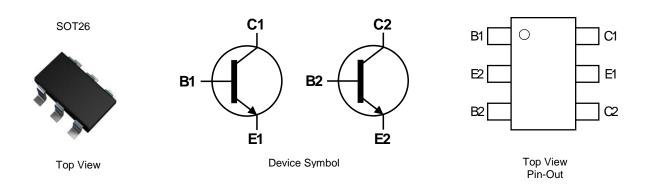
80V DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features & Benefits

- BV_{CEO} > 80V
- I_{CM} = 1A Peak Pulse Current
- General purpose NPN transistors ideally suited for low power amplification and switching applications
- Dual transistors in a single SOT26 package taking half the footprint of two equivalent transistors in SOT23
- Epitaxial Planar Die Construction
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 <a>3
- Weight: 0.015 grams (Approximate)



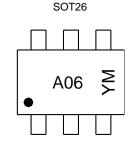
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMDTA06-7	A06	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



A06 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2015	2	016	2017	2018	2019	2020	202	1 20	22	2023	2024	2025
Code	С		D	Е	F	G	Н	- 1	,	J	K	L	М
Montl	h	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	100	V
Collector-Emitter Voltage	V _{CEO}	80	V
Emitter-Base Voltage	V _{EBO}	6	V
Continuous Collector Current	Ic	500	mA
Peak Pulse Collector Current	I _{CM}	1	Α

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Power Dissipation	(Notes 6 & 7)	5	1.28 10.3	W
Linear Derating Factor	(Notes 5 & 7)	P_D	0.90 7.14	mW/°C
Thermal Resistance, Junction to Ambient	(Notes 6 & 7) (Notes 5 & 7)	$R_{ hetaJA}$	97 140	°C/W
Thermal Resistance, Junction to Lead	(Note 8)	$R_{ heta JL}$	103	
Operating and Storage Temperature Range		T_{J}, T_{STG}	-55 to +150	°C

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

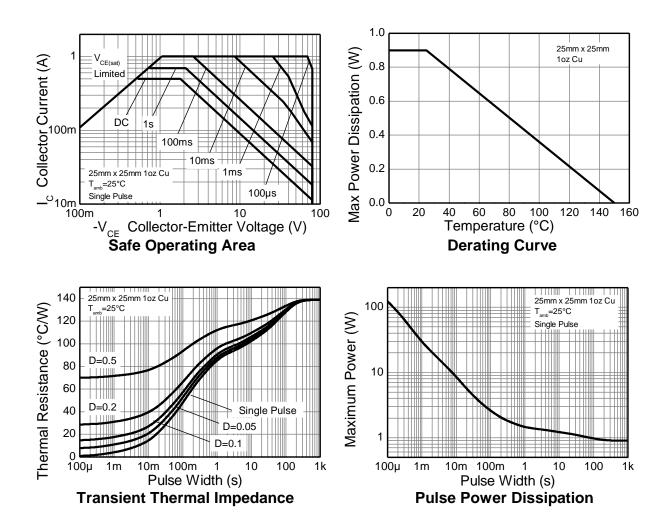
Notes:

- 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Same as Note 5, except the device is measured at $t \le 5$ seconds.
- 7. For a dual device with one active die.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





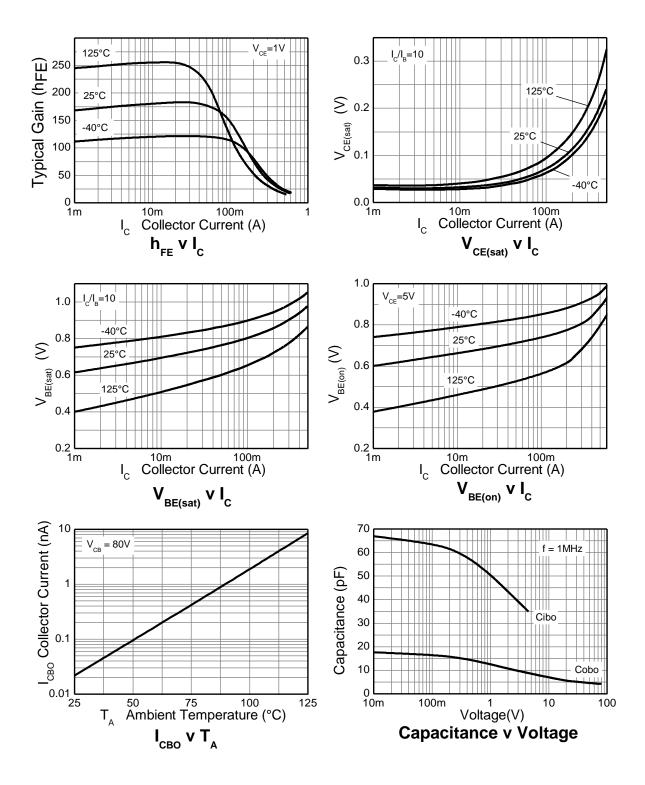
Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	100	_	_	V	$I_C = 100\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	80	_	_	V	$I_{C} = 1 \text{mA}, I_{B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6	_	_	V	$I_E = 100 \mu A, I_C = 0$
Collector-Base Cut-Off Current	I _{CBO}	_	_	100	nA	$V_{CB} = 80V, I_{E} = 0$
Collector-Emitter Cut-Off Current	I _{CES}	_	_	100	nA	$V_{CE} = 80V, I_B = 0$
Emitter-base Cut-Off Current	I _{EBO}	_	_	100	nA	$V_{EB} = 5V, I_{C} = 0$
ON CHARACTERISTICS (Note 10)						
DC Current Gain	h	100	_			$I_C = 10$ mA, $V_{CE} = 1$ V
DC Current Gain	h _{FE}	100	_			$I_C = 100 \text{mA}, V_{CE} = 1 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}			0.25	V	$I_C = 100 \text{mA}, I_B = 10 \text{mA}$
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	_	1.20	V	I _C = 100mA, V _{CE} = 1V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f⊤	100	163		MHz	V _{CE} = 2V, I _C = 10mA, f = 100MHz
Output Capacitance	$C_{ m obo}$	_	7	_	pF	V _{CB} = 10V, f = 1MHz

Note: 10. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.

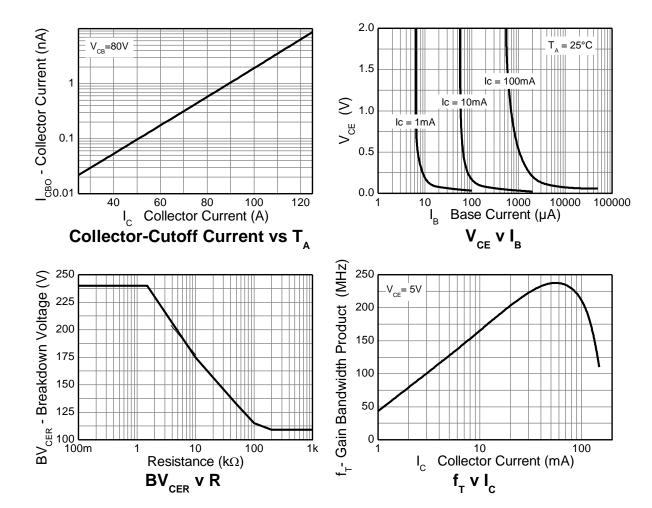


Typical Electrical Characteristics (@T_A = +25°C unless otherwise specified.)





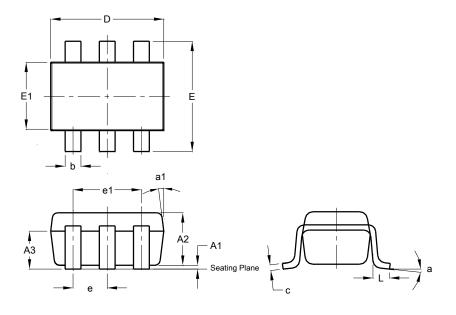
Typical Electrical Characteristics – Continued (@T_A = +25°C unless otherwise specified.)





Package Outline

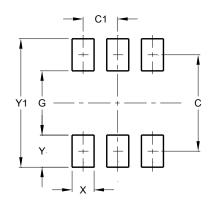
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26						
Dim	Min	Max	Тур				
A1	0.013	0.10	0.05				
A2	1.00	1.30	1.10				
А3	0.70	0.80	0.75				
b	0.35	0.50	0.38				
С	0.10	0.20	0.15				
D	2.90	3.10	3.00				
е	-	-	0.95				
e1	-	-	1.90				
Е	2.70	3.00	2.80				
E1	1.50	1.70	1.60				
L	0.35	0.55	0.40				
а	-	-	8°				
a1	-	-	7°				
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Υ	0.80
Y1	3.20



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